



REF2912 REF2920 REF2925 REF2930 REF2933 REF2940

SBVS033A - JUNE 2002 - REVISED MARCH 2003

100ppm/°C, 50μA in SOT23-3 CMOS VOLTAGE REFERENCE

FEATURES

● MicroSIZE PACKAGE: SOT23-3

● LOW DROPOUT: 1mV

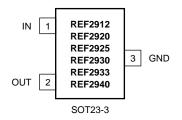
● HIGH OUTPUT CURRENT: 25mA

● LOW TEMPERATURE DRIFT: 100ppm/°C max

HIGH ACCURACY: 2%
 LOW I₀: 50µA max

APPLICATIONS

- PORTABLE, BATTERY-POWERED EQUIPMENT
- DATA ACQUISITION SYSTEMS
- MEDICAL EQUIPMENT
- HAND-HELD TEST EQUIPMENT



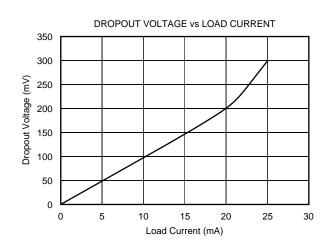
DESCRIPTION

The REF29xx is a precision, low-power, low-voltage dropout voltage reference family available in a tiny SOT23-3.

The REF29xx's small size and low power consumption ($50\mu A$ max) make it ideal for portable and battery-powered applications. The REF29xx does not require a load capacitor, but is stable with any capacitive load.

Unloaded, the REF29xx can be operated with supplies within 1mV of output voltage. All models are specified for the wide temperature range, -40°C to +125°C.

PRODUCT	VOLTAGE (V)
REF2912	1.25
REF2920	2.048
REF2925	2.5
REF2930	3.0
REF2933	3.3
REF2940	4.096





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ABSOLUTE MAXIMUM RATINGS(1)

Supply Voltage, V+ to V	7.0V
Output Short-Circuit ⁽²⁾	Continuous
Operating Temperature	40°C to +125°C
Storage Temperature	
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C

NOTES: (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these, or any other conditions beyond those specified, is not implied. (2) Short-circuit to ground.

ELECTROSTATIC DISCHARGE SEN

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with

ments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR ⁽¹⁾	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
REF2912	SOT23-3	DBZ "	-40°C to +125°C	R29A "	REF2912AIDBZT REF2912AIDBZR	Tape and Reel, 250 Tape and Reel, 3000
REF2920	SOT23-3	DBZ "	-40°C to +125°C	R29B "	REF2920AIDBZT REF2920AIDBZR	Tape and Reel, 250 Tape and Reel, 3000
REF2925	SOT23-3	DBZ "	-40°C to +125°C	R29C "	REF2925AIDBZT REF2925AIDBZR	Tape and Reel, 250 Tape and Reel, 3000
REF2930	SOT23-3	DBZ "	–40°C to +125°C	R29D "	REF2930AIDBZT REF2930AIDBZR	Tape and Reel, 250 Tape and Reel, 3000
REF2933	SOT23-3	DBZ "	-40°C to +125°C	R29E "	REF2933AIDBZT REF2933AIDBZR	Tape and Reel, 250 Tape and Reel, 3000
REF2940	SOT23-3	DBZ "	–40°C to +125°C	R29F "	REF2940AIDBZT REF2940AIDBZR	Tape and Reel, 250 Tape and Reel, 3000

NOTE: (1) For the most current specifications and package information, refer to our web site at www.ti.com.

ELECTRICAL CHARACTERISTICS

Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$.

At $T_A = +25^{\circ}C$, $I_{LOAD} = 0$ mA, $V_{IN} = 5$ V, unless otherwise noted.

				REF29xx				
PARAMETER		CONDITIONS	MIN	TYP	MAX	UNITS		
		REF2912-1.25V						
OUTPUT VOLTAGE Initial Accuracy	V _{OUT}		1.225	1.25	1.275 2	V %		
NOISE Output Voltage Noise Voltage Noise		f = 0.1Hz to 10Hz f = 10Hz to 10kHz		20 42		μVp-p μVrms		
LINE REGULATION		$1.8V \le V_{IN} \le 5.5V$		60	190	μV/V		
	•	REF2920		•				
OUTPUT VOLTAGE Initial Accuracy	V _{OUT}		2.007	2.048	2.089 2	V %		
NOISE Output Voltage Noise Voltage Noise		f = 0.1Hz to 10Hz f = 10Hz to 10kHz		28 65		μVp-p μVrms		
LINE REGULATION		V_{REF} + 50mV $\leq V_{IN} \leq 5.5V$		110	290	μV/V		
		REF2925						
OUTPUT VOLTAGE Initial Accuracy	V _{OUT}		2.450	2.50	2.550 2	V %		
NOISE Output Voltage Noise Voltage Noise		f = 0.1Hz to 10Hz f = 10Hz to 10kHz		35 80		μVp-p μVrms		
LINE REGULATION		V_{REF} + 50mV $\leq V_{IN} \leq 5.5V$		120	325	μV/V		

ELECTRICAL CHARACTERISTICS (Cont.)

Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$.

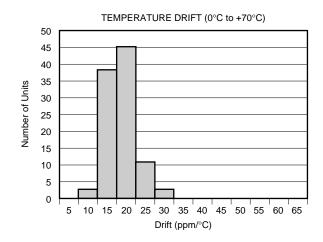
At T_A = +25°C, I_{LOAD} = 0mA, V_{IN} = 5V, unless otherwise noted.

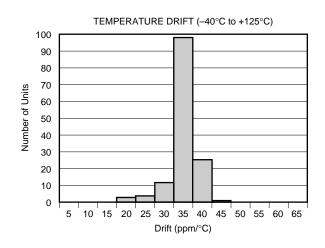
			REF29xx		
PARAMETER	CONDITIONS	MIN	MIN TYP MAX		
	REF2930	•			
OUTPUT VOLTAGE V _{OUT}		2.940	3.0	3.06 2	V %
NOISE Output Voltage Noise Voltage Noise	f = 0.1Hz to 10Hz f = 10Hz to 10kHz				μVp-p μVrms
LINE REGULATION	V_{REF} + 50mV $\leq V_{IN} \leq 5.5V$		120	375	μV/V
	REF2933	•			
OUTPUT VOLTAGE V _{OUT}		3.234	3.30	3.366 2	V %
NOISE Output Voltage Noise Voltage Noise	f = 0.1Hz to 10Hz f = 10Hz to 10kHz		41 105		μVp-p μVrms
LINE REGULATION	V_{REF} + $50mV \le V_{IN} \le 5.5V$		130	400	μV/V
	REF2940				
OUTPUT VOLTAGE V _{OUT}		4.014	4.096	4.178 2	V %
NOISE Output Voltage Noise Voltage Noise	f = 0.1Hz to 10Hz f = 10Hz to 10kHz		45 128		μVp-p μVrms
LINE REGULATION	$V_{REF} + 50 \text{mV} \le V_{IN} \le 5.5 \text{V}$		160	410	μV/V
REF2912, REF	72920, REF2925, REF2930, REF	2933, REF294	0		
OUTPUT VOLTAGE TEMP DRIFT ⁽²⁾ dV _{OUT} /dT	-40°C ≤ T _A ≤ +125°C		35	100	ppm/°C
OUTPUT CURRENT I _{LOAD}	*			25	mA
LONG-TERM STABILITY	0-1000 _H 1000-2000 _H		24 15		ppm ppm
LOAD REGULATION ⁽³⁾ dV _{OUT} /dl _{LOAD}	$0mA < I_{LOAD} < 25mA,$ $V_{IN} = V_{REF} + 500mV^{(1)}$		3	100	μV/mA
THERMAL HYSTERESIS(4) dT			25	100	ppm
DROPOUT VOLTAGE V _{IN} - V _{OUT}			1	50	mV
SHORT-CIRCUIT CURRENT I _{SC}			45		mA
TURN-ON SETTLING TIME	to 0.1% at $V_{IN} = 5V$ with $C_L = 0$		120		μs
POWER SUPPLY Voltage V _S Over Temperature Quiescent Current I _Q Over Temperature I _Q	$I_{L} = 0$ $-40^{\circ}C \le T_{A} \le +125^{\circ}C$ $-40^{\circ}C \le T_{A} \le +125^{\circ}C$	V _{REF} + 0.001 ⁽⁵⁾ V _{REF} + 0.05	42	5.5 5.5 50 59	V V μΑ μ A
TEMPERATURE RANGE Specified Range Operating Range Storage Range Thermal Resistance		-40 -40 -65		+125 +125 +150	ο̈ο̈ο̈
SOT23-3 Surface-Mount θ_{JC} θ_{JA}			110 336		°C/W

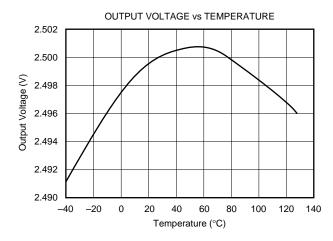
NOTES: (1) Minimum supply voltage for REF2912 is 1.8V. (2) Box Method used to determine over temperature drift. (3) Typical value of load regulation reflects measurements using a force and sense contacts, see text "Load Regulation". (4) Thermal hysteresis procedure is explained in more detail in Applications Information section of data sheet. (5) For $I_L > 0$, see Typical Characteristic curves.

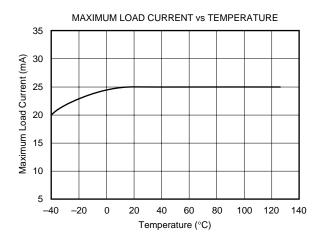
TYPICAL CHARACTERISTICS

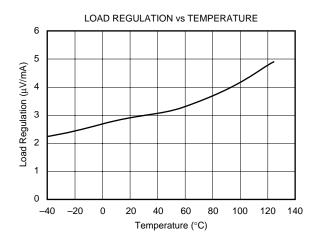
At $T_A = +25$ °C, $V_{IN} = +5$ V power supply, REF2925 is used for typical characteristics, unless otherwise noted.

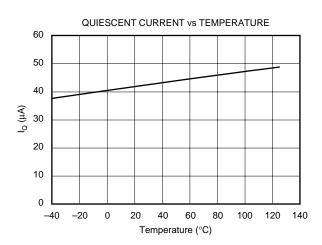






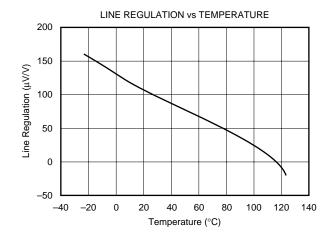


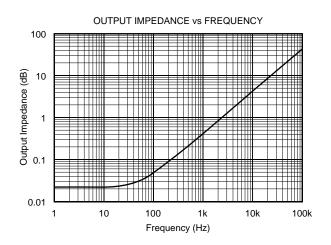


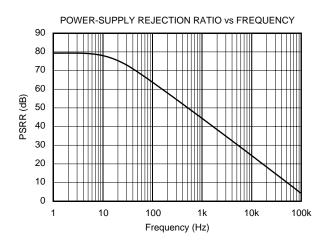


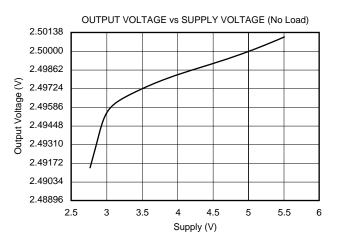
TYPICAL CHARACTERISTICS (Cont.)

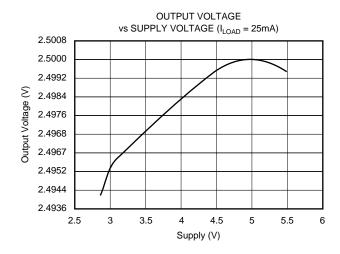
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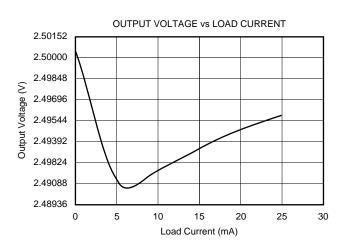






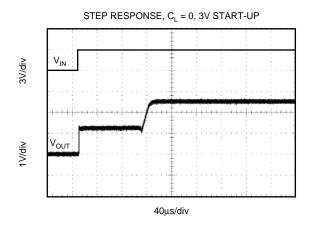


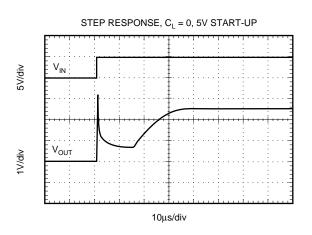


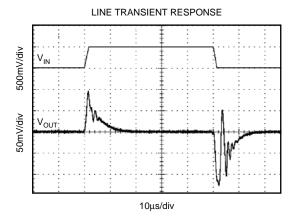


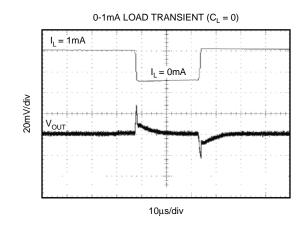
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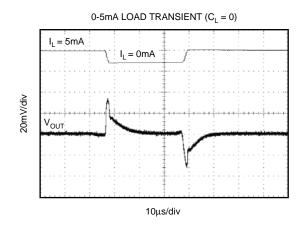
At $T_A = +25^{\circ}C$, $V_{IN} = +5V$ power supply, REF2925 is used for typical characteristics, unless otherwise noted.

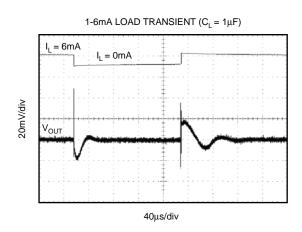






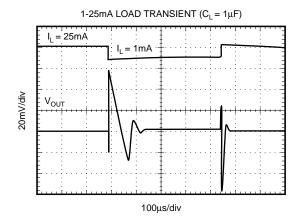


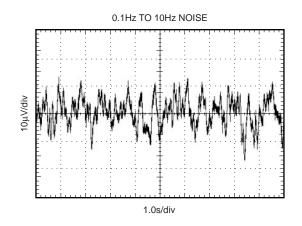


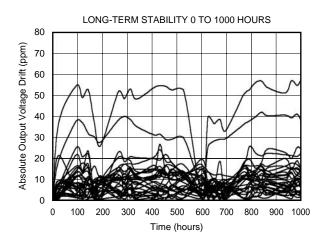


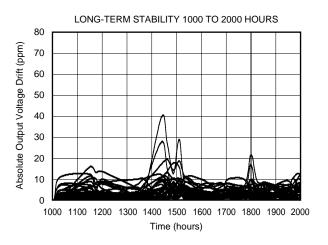
TYPICAL CHARACTERISTICS (Cont.)

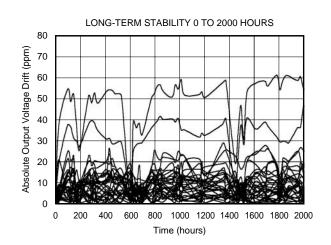
At $T_A = +25$ °C, $V_{IN} = +5V$ power supply, REF2925 is used for typical characteristics, unless otherwise noted.











THEORY OF OPERATION

The REF29xx is a series, CMOS, precision bandgap voltage reference. It's basic topology is shown in Figure 1. The transistors Q_1 , and Q_2 , are biased such that the current density of Q_1 is greater than that of Q_2 . The difference of the two base-emiter voltages, $Vbe_1 - Vbe_2$, has a positive temperature coefficient and is forced across resistor R_1 . This voltage is gained up and added to the base-emitter voltage of Q_2 , which has a negative coefficient. The resulting output voltage is virtually independent of temperature. The curvature of the bandgap voltage, as seen in the typical curve, "Output Voltage vs Temperature", is due to the slightly nonlinear temperature coefficient of the base-emitter voltage of Q_2 .

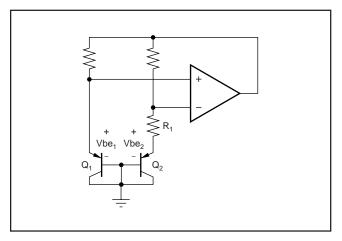


FIGURE 1. Simplified Schematic of Bandgap Reference.

APPLICATION INFORMATION

The REF29xx does not require a load capacitor, and is stable with any capacitive load. Figure 2 shows typical connections required for operation of the REF29xx. A supply bypass capacitor of $0.47\mu F$ is recommended.

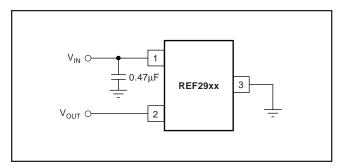


FIGURE 2. Typical Connections for Operating REF29xx.

SUPPLY VOLTAGE

The REF29xx family of references features an extremely low dropout voltage. With the exception of the REF2912, which has a minimum supply requirement of 1.8V, the REF29xx can be operated with a supply of only 1mV above the output voltage in an unloaded condition. For loaded conditions, a typical dropout voltage versus load is shown on the cover page.

The REF29xx features a low quiescent current, which is extremely stable over changes in both temperature and supply. The typical room temperature quiescent current is 42 μ A, and the maximum quiescent current over temperature is just 59 μ A. Additionally, the quiescent current typically changes less than 2.5 μ A over the entire supply range, as shown in Figure 3.

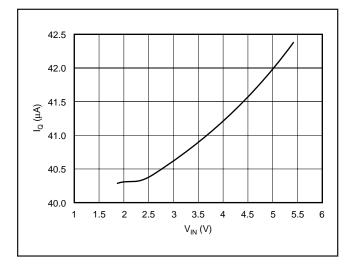


FIGURE 3. Supply Current vs Supply Voltage.

Supply voltages below the specified levels can cause the REF29xx to momentarily draw currents greater than the typical quiescent current. Using a power supply with a fast rising edge and low output impedance easily prevents this.

THERMAL HYSTERESIS

Thermal hysteresis for the REF29xx is defined as the change in output voltage after operating the device at 25°C, cycling the device through the specified temperature range, and returning to 25°C, and can be expressed as:

$$V_{HYST} = \left(\frac{abs|V_{PRE} - V_{POST}|}{V_{NOM}}\right) \bullet 10^{6} (ppm)$$

Where: $V_{HYST} = Calculated$ hysteresis

 V_{PRE} = Output voltage measured at 25°C pretemperature cycling

V_{POST} = Output voltage measured when device has been operated at 25°C, cycled through specified range –40°C to +125°C and returned to operation at 25°C

TEMPERATURE DRIFT

The REF29xx is designed to exhibit minimal drift error, defined as the change in output voltage over varying temperature. Using the 'box' method of drift measurement, the REF29xx features a typical drift coefficient of 20ppm from 0°C to 70°C—the primary temperature range of use for many applications. For industrial temperature ranges of -40°C to 125°C, the REF29xx family drift increases to a typical value of 50ppm.

NOISE PERFORMANCE

The REF29xx generates noise less than $50\mu\text{Vp-p}$ between frequencies of 0.1Hz to 10Hz, and can be seen in the Typical Characteristic Curve "0.1 to 10Hz Voltage Noise". The noise voltage of the REF29xx increases with output voltage and operating temperature. Additional filtering may be used to improve output noise levels, although care should be taken to ensure the output impedance does not degrade AC performance.

LONG TERM STABILITY

Long term stability refers to the change of the output voltage of a reference over a period of months or years. This effect lessens as time progresses as is apparent by the long term stability curves. The typical drift value for the REF29xx is 24ppm from 0-1000 hours, and 15ppm from 1000-2000 hours. This parameter is characterized by measuring 30 units at regular intervals for a period of 2000 hours.

LOAD REGULATION

Load regulation is defined as the change in output voltage due to changes in load current. Load regulation for the REF29xx is measured using force and sense contacts as pictured in Figure 4. The force and sense lines tied to the

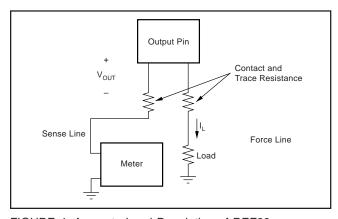


FIGURE 4. Accurate Load Regulation of REF29xx.

contact area of the output pin reduce the impact of contact and trace resistance, resulting in accurate measurement of the load regulation contributed solely by the REF29xx. For applications requiring improved load regulation, force and sense lines should be used.

APPLICATION CIRCUITS

Negative Reference Voltage

For applications requiring a negative and positive reference voltage, the OPA703 and REF29xx can be used to provide a dual supply reference from a ± 5 V supply. Figure 5 shows the REF2925 used to provide a ± 2.5 V supply reference voltage. The low offset voltage and low drift of the OPA703 complement the low drift performance of the REF29xx to provide an accurate solution for split-supply applications.

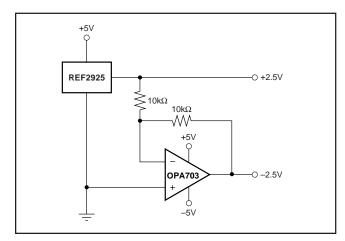


FIGURE 5. REF2925 Combined with OPA703 to Create Positive and Negative Reference Voltages.

DATA ACQUISITION

Often data acquisition systems require stable voltage references to maintain necessary accuracy. The REF29xx family features stability and a wide range of voltages suitable for most micro-controllers and data converters. See Figure 6 for a basic data acquisition system.

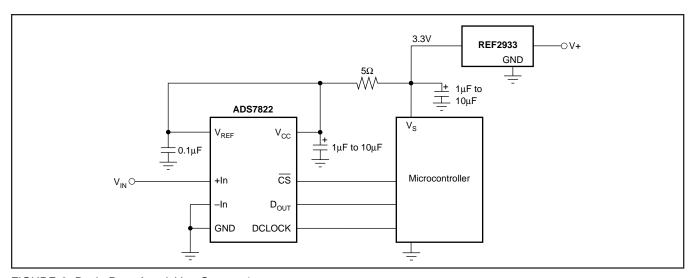


FIGURE 6. Basic Data Acquisition System 1.





PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
REF2912AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2912AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2912AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2912AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2920AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2920AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2920AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2920AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2925AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2925AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2925AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2925AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2930AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2930AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2930AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2930AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2933AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2933AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2933AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2933AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2940AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2940AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2940AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
REF2940AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

 $^{^{(1)}}$ The marketing status values are defined as follows:



PACKAGE OPTION ADDENDUM

18-Jul-2006

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

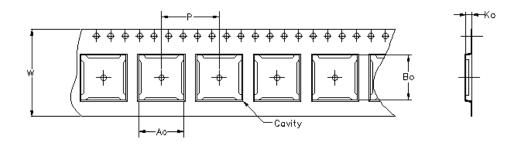
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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Carrier tape design is defined largely by the component lentgh, width, and thickness.

Ao =	Dimension	designed	to	accommodate	the	component	width.	
Bo =	Dimension	designed	to	accommodate	the	component	length.	
Ko =	Dímension	designed	to	accommodate	the	component	thickness.	
W = Overall width of the carrier tape.								
P = F	P = Pitch between successive cavity centers.							



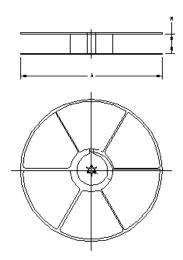
TAPE AND REEL INFORMATION





7-May-2007

Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
REF2912AIDBZR	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2912AIDBZT	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2920AIDBZR	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2920AIDBZT	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2925AIDBZR	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2925AIDBZT	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2930AIDBZR	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2930AIDBZT	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2933AIDBZR	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2933AIDBZT	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2940AIDBZR	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE
REF2940AIDBZT	DBZ	3	NSE	177	8	3.15	2.95	1.22	4	8	NONE



TAPE AND REEL BOX INFORMATION

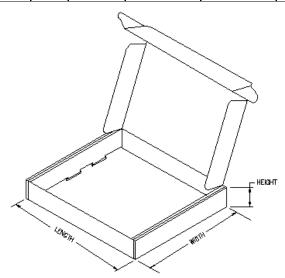
Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
REF2912AIDBZR	DBZ	3	NSE	195.0	200.0	45.0
REF2912AIDBZT	DBZ	3	NSE	195.0	200.0	45.0
REF2920AIDBZR	DBZ	3	NSE	195.0	200.0	45.0
REF2920AIDBZT	DBZ	3	NSE	195.0	200.0	45.0
REF2925AIDBZR	DBZ	3	NSE	195.0	200.0	45.0
REF2925AIDBZT	DBZ	3	NSE	195.0	200.0	45.0
REF2930AIDBZR	DBZ	3	NSE	195.0	200.0	45.0
REF2930AIDBZT	DBZ	3	NSE	195.0	200.0	45.0
REF2933AIDBZR	DBZ	3	NSE	195.0	200.0	45.0



PACKAGE MATERIALS INFORMATION

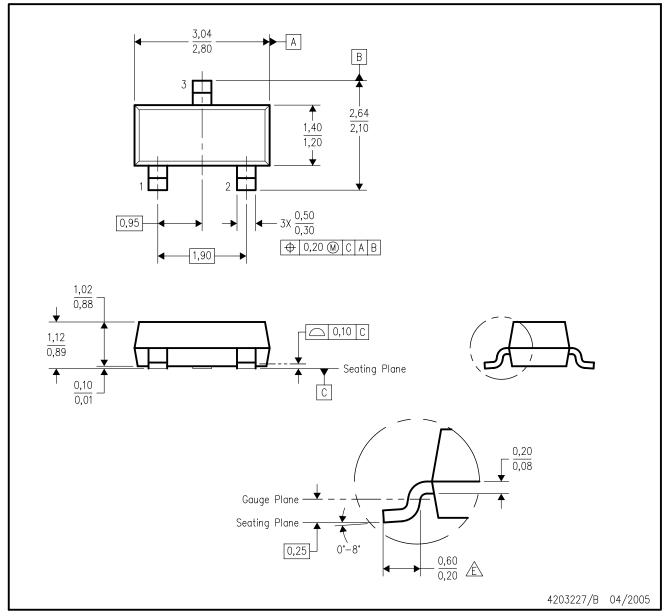
7-May-2007

Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
REF2933AIDBZT	DBZ	3	NSE	195.0	200.0	45.0
REF2940AIDBZR	DBZ	3	NSE	195.0	200.0	45.0
REF2940AIDBZT	DBZ	3	NSE	195.0	200.0	45.0



DBZ (R-PDSO-G3)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Lead dimensions are inclusive of plating.
- D. Body dimensions are exclusive of mold flash and protrusion. Mold flash and protrusion not to exceed 0.25 per side.
- Falls within JEDEC TO-236 variation AB, except minimum foot length.



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